

60/709869

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	85	EPROM and (tunnel adj oxide) and n-type and p-type and channel and floating and gate and control and source and drain and region and polysilicon and electrode and voltage and transistor and band	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 17:42
L6	1	("6426254").PN.	USPAT	OR	OFF	2005/08/16 17:43